



BC847CPN

DUAL GENERAL PURPOSE TRANSISTORS

NPN/PNP Duals (Complimentary)

These transistors are designed for general purpose amplifier applications. They are housed in the SOT-363 which is designed for low power surface mount applications.

FEATURES

- In compliance with EU RoHS 2002/95/EC directives

MECHANICAL DATA

Case: SOT-363

Terminals : Solderable per MIL-STD-750, Method 2026

Approx Weight: 0.006 grams

Marking : 4C7

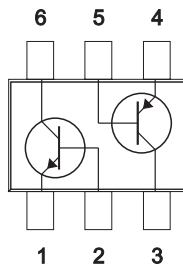
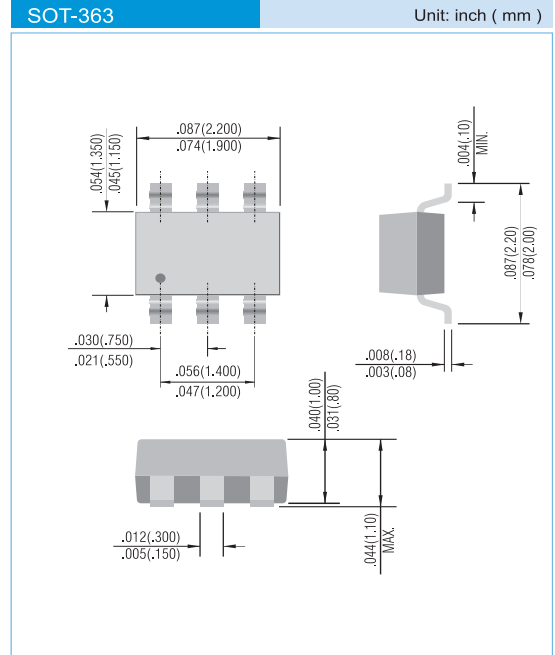


Fig.55



MAXIMUM RATINGS-NPN

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	45	V
Collector-Base Voltage	V_{CBO}	50	V
Emitter-Base Voltage	V_{EBO}	6.0	V
Collector Current-Continuous	I_c	100	mAdc

MAXIMUM RATINGS-PNP

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	-45	V
Collector-Base Voltage	V_{CBO}	-50	V
Emitter-Base Voltage	V_{EBO}	-5.0	V
Collector Current-Continuous	I_c	-100	mAdc

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



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THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation Per Device FR-4 Board (Note 1) $T_A=25^\circ\text{C}$ Derate above 25°C	P_D	380	mW
		250	
		3.0	mW/ $^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	328	$^\circ\text{C}/\text{W}$
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 to +150	$^\circ\text{C}$

1.FR-4 = 70 x 60 x 1mm.

ELECTRICAL CHARACTERISTICS (NPN) ($T_A=25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min.	Typ.	Max.	Unit
OFF CHARACTERISTICS					
Collector-Emitter Breakdown Voltage $I_C=10\text{mA}$	$V_{(BR)CEO}$	45	-	-	V
Collector-Emitter Breakdown Voltage $I_C=10\mu\text{A}, V_{EB}=0$	$V_{(BR)CES}$	50	-	-	V
Collector-Base Breakdown Voltage $I_C=10\mu\text{A}$	$V_{(BR)CBO}$	50	-	-	V
Emitter-Base Breakdown Voltage $I_E=1.0\mu\text{A}$	$V_{(BR)EBO}$	6.0	-	-	V
Collector Cutoff Current $V_{CB}=30\text{V}$ $V_{CB}=30\text{V}, T_A=150^\circ\text{C}$	I_{CBO}	-	-	15 5.0	nA μA
ON CHARACTERISTICS					
DC Current Gain $I_C=10\mu\text{A}, V_{CE}=5.0\text{V}$ $I_C=2.0\text{mA}, V_{CE}=5.0\text{V}$	h_{FE}	- 420	270 520	- 800	-
Collector-Emitter Saturation Voltage $I_C=10\text{mA}, I_B=0.5\text{mA}$ $I_C=100\text{mA}, I_B=5.0\text{mA}$	$V_{CE(sat)}$	- -	- -	0.25 0.6	V
Base-Emitter Saturation Voltage $I_C=10\text{mA}, I_B=0.5\text{mA}$ $I_C=100\text{mA}, I_B=5.0\text{mA}$	$V_{BE(sat)}$	- -	0.7 0.9	- -	V
Base-Emitter Voltage $I_C=2.0\text{mA}, V_{CE}=5.0\text{V}$ $I_C=10\text{mA}, V_{CE}=5.0\text{V}$	$V_{BE(on)}$	580 -	660 -	700 770	mV
SMALL-SIGNAL CHARACTERISTICS					
Current-Gain-Bandwidth Product $I_C=10\text{mA}, V_{CE}=5.0\text{Vdc}, f=100\text{MHz}$	fr	100	-	-	MHz
Output Capacitance ($V_{CB}=10\text{V}, f=1\text{MHz}$)	Cobo	-	-	4.5	pF
Noise Figure $I_C=0.2\text{mA}, V_{CE}=5.0\text{Vdc}, R_S=2.0\text{k}\Omega, f=1.0\text{kHz}, BW=200\text{Hz}$	NF	-	-	10	dB



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ELECTRICAL CHARACTERISTICS (PNP) (T_A=25°C unless otherwise noted)

Characteristic	Symbol	Min.	Typ.	Max.	Unit
OFF CHARACTERISTICS					
Collector-Emitter Breakdown Voltage I _C =-10mA	V _{(BR)CEO}	-45	-	-	V
Collector-Emitter Breakdown Voltage I _C =-10μA, V _{EB} =0	V _{(BR)CES}	-50	-	-	V
Collector-Base Breakdown Voltage I _C =-10μA	V _{(BR)CBO}	-50	-	-	V
Emitter-Base Breakdown Voltage I _E =-1.0μA	V _{(BR)EBO}	-5.0	-	-	V
Collector Cutoff Current V _{CB} =-30V V _{CB} =-30V, T _A =150°C	I _{CBO}	-	-	-15 -4.0	nA μA
ON CHARACTERISTICS					
DC Current Gain I _C =-10μA, V _{CE} =-5.0V I _C =-2.0mA, V _{CE} =-5.0V	h _{FE}	- 420	270 520	- 800	-
Collector-Emitter Saturation Voltage I _C =-10mA, I _B =-0.5mA I _C =-100mA, I _B =-5.0mA	V _{CE(sat)}	- -	- -	-0.3 -0.65	V
Base-Emitter Saturation Voltage I _C =-10mA, I _B =-0.5mA I _C =-100mA, I _B =-5.0mA	V _{BE(sat)}	- -	-0.7 -0.9	- -	V
Base-Emitter Voltage I _C =-2.0mA, V _{CE} =-5.0V I _C =-10mA, V _{CE} =-5.0V	V _{BE(on)}	-0.6 -	- -	-0.75 -0.82	mV
SMALL-SIGNAL CHARACTERISTICS					
Current-Gain-Bandwidth Product I _C =-10mA, V _{CE} =-5.0Vdc, f=100MHz	f _T	100	-	-	MHz
Output Capacitance (V _{CB} =-10V, f=1MHz)	C _{obo}	-	-	4.5	pF
Noise Figure I _C =-0.2mA, V _{CE} =-5.0Vdc, R _S =2.0kΩ, 1.0kHz, BW=200Hz	NF	-	-	10	dB



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TYPICAL NPN CHARACTERISTICS

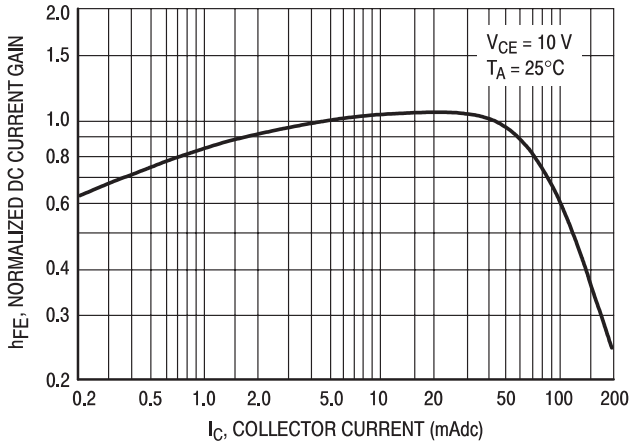


Figure 1 . Normalized DC Current Gain

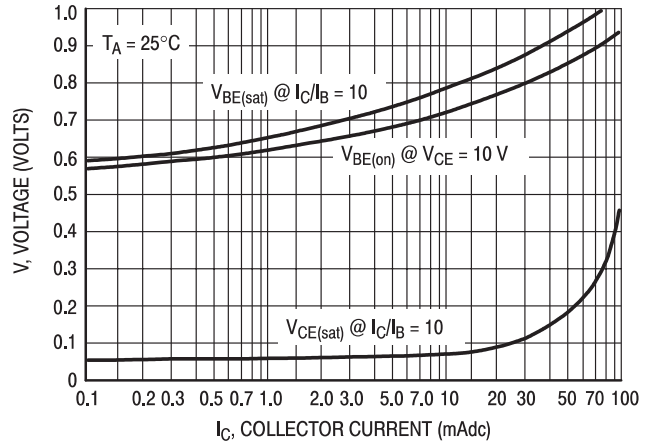


Figure 2 . "Saturation" and "On" Voltages

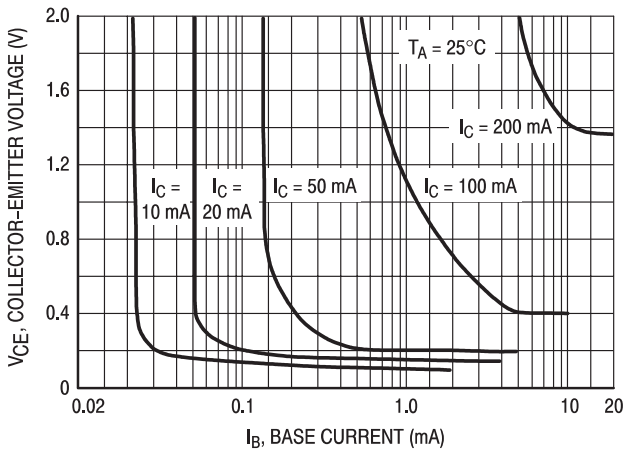


Figure 3 . Collector Saturation Region

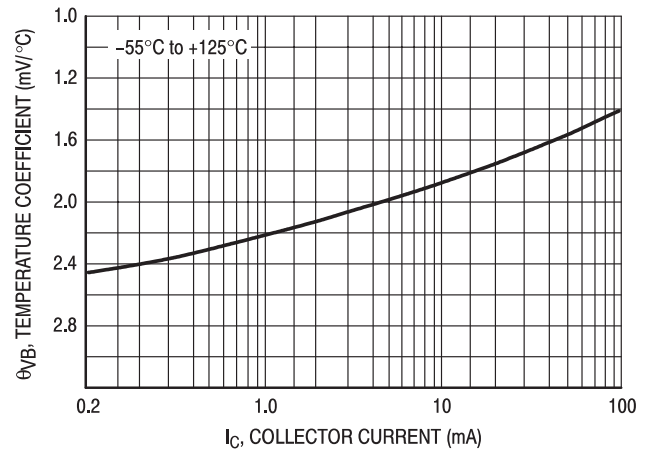


Figure 4 . Base-Emitter Temperature Coefficient

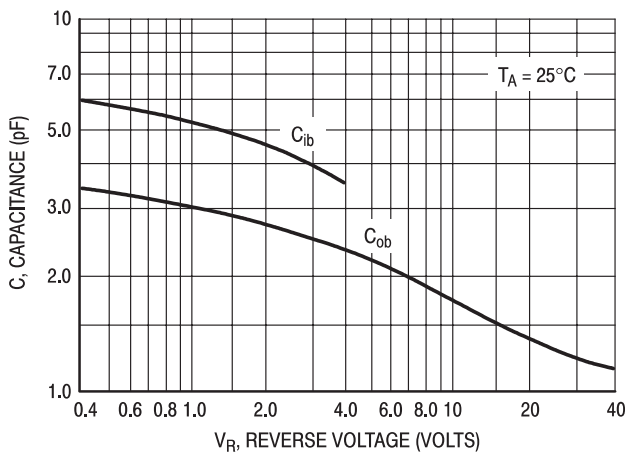


Figure 5 . Capacitances

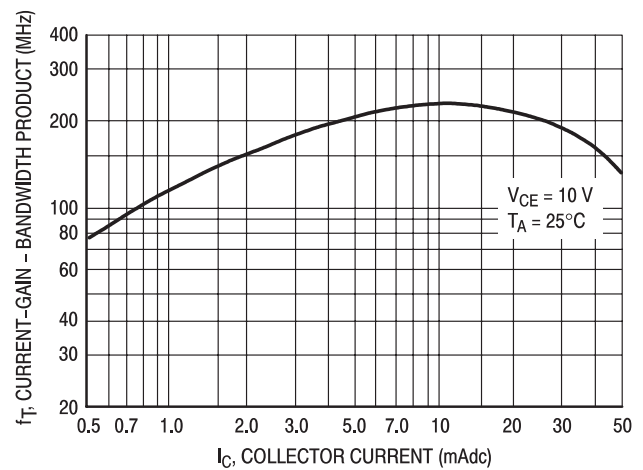


Figure 6 . Current-Gain - Bandwidth Product



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TYPICAL PNP CHARACTERISTICS

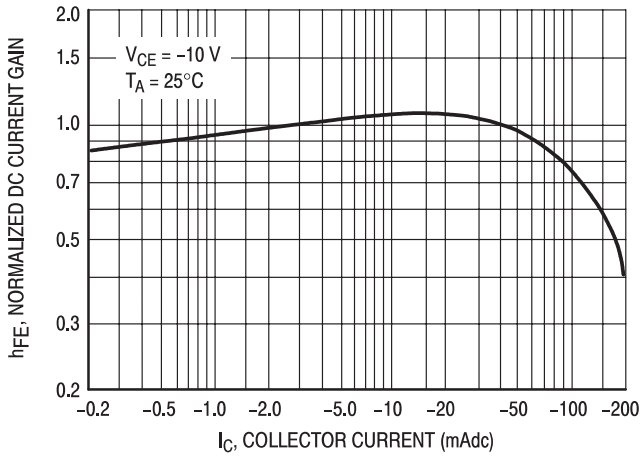


Figure 7 . Normalized DC Current Gain

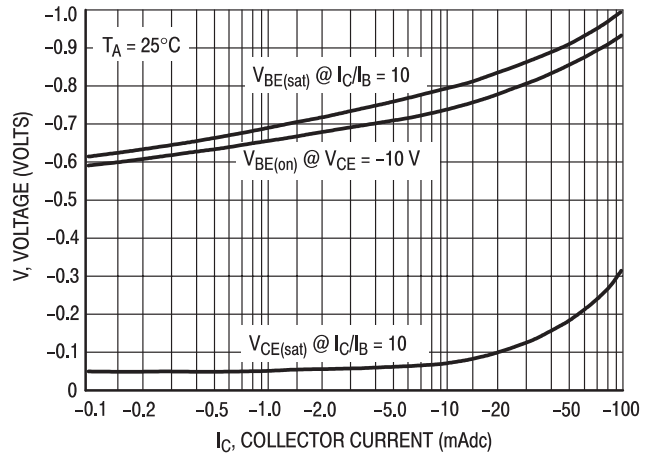


Figure 8 . "Saturation" and "On" Voltages

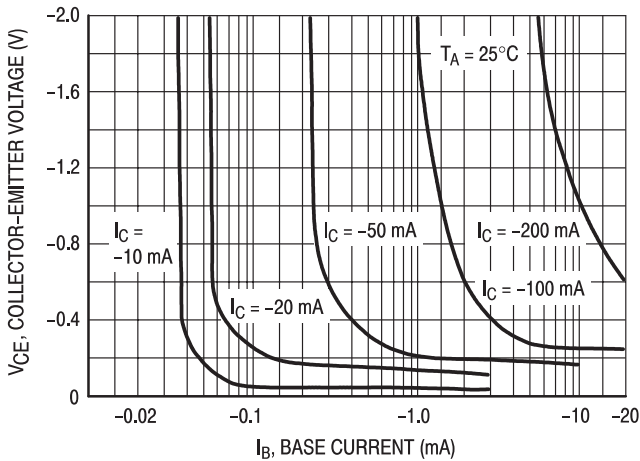


Figure 9 . Collector Saturation Region

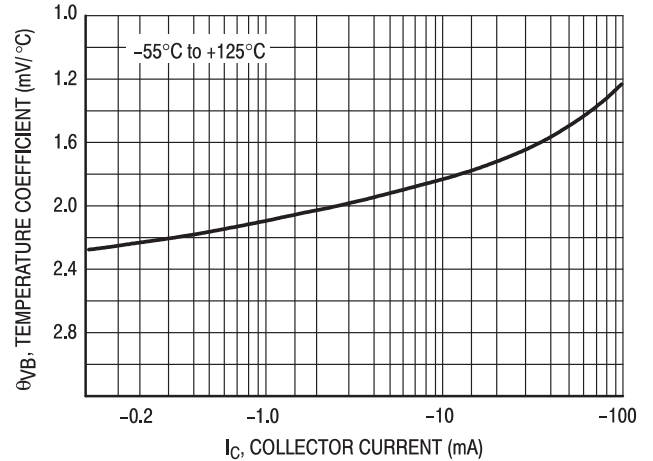


Figure 10 . Base-Emitter Temperature Coefficient

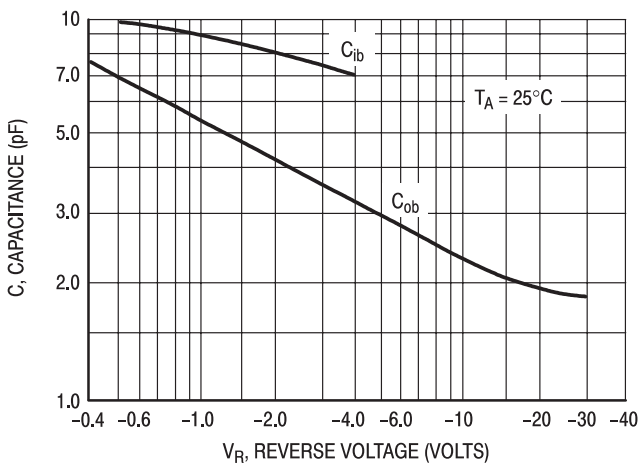


Figure 11 . Capacitances

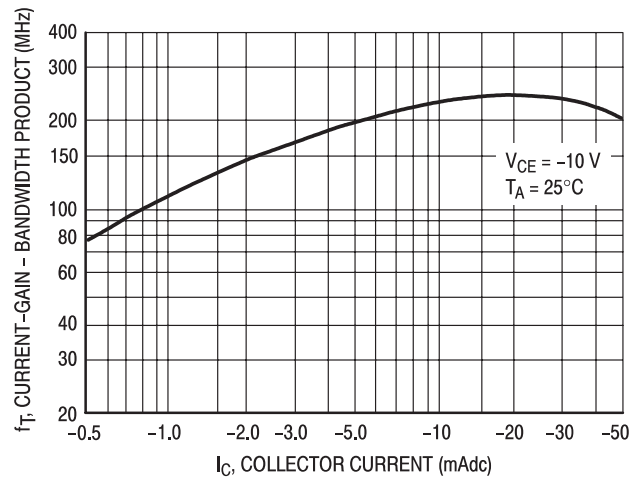


Figure 12 . Current-Gain - Bandwidth Product



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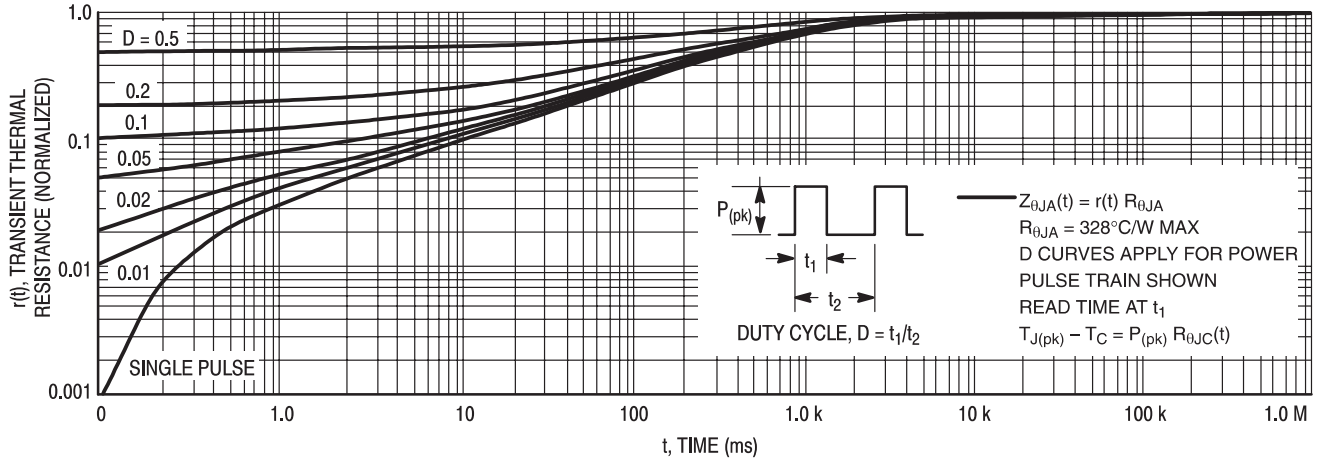


Figure 13. Thermal Response

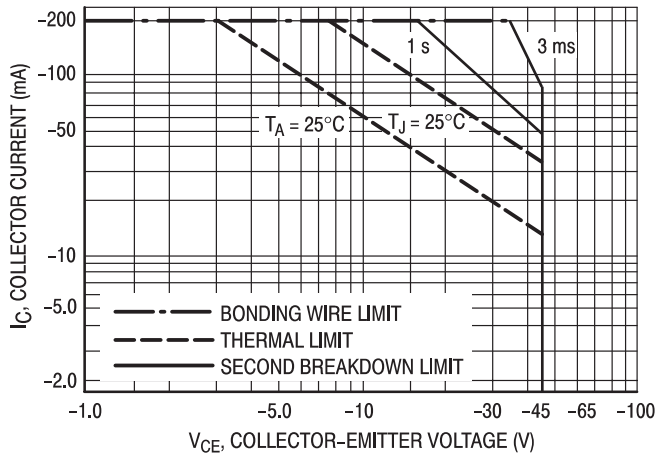


Figure 14 . Active Region Safe Operating Area

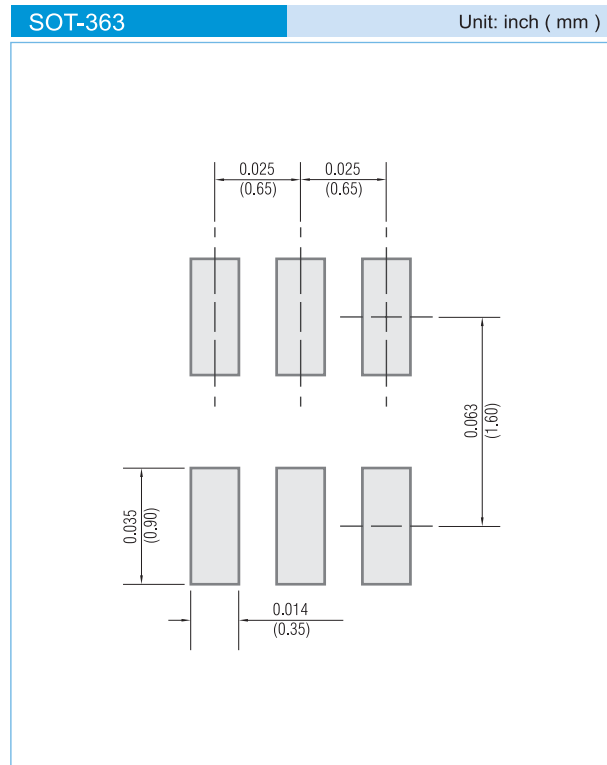
The safe operating area curves indicate I_C – V_{CE} limits of the transistor that must be observed for reliable operation. Collector load lines for specific circuits must fall below the limits indicated by the applicable curve.

The data of Figure 26 is based upon $T_{J(pk)} = 150^\circ\text{C}$; T_C or T_A is variable depending upon conditions. Pulse curves are valid for duty cycles to 10% provided $T_{J(pk)} \leq 150^\circ\text{C}$. $T_{J(pk)}$ may be calculated from the data in Figure 25. At high case or ambient temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by the secondary breakdown.



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MOUNTING PAD LAYOUT



ORDER INFORMATION

- Packing information
 - T/R - 10K per 13" plastic Reel
 - T/R - 3K per 7" plastic Reel

LEGAL STATEMENT

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